











TPS2559-Q1

SLVSD03-DECEMBER 2015

TPS2559-Q1 Precision Adjustable Current-Limited Power-Distribution Switch

Features

- Qualified for Automotive Applications AEC-Q100 Qualified With the Following Results:
 - Device HBM ESD Classification Level H2
 - Device CDM ESD Classification Level C5
- 2.5 to 6.5 V Operating Range
- Adjustable 1.2 to 4.7 A $I_{(LIMIT)}$ (±4.7% at 4.7 A)
- 3.5 µs Short Circuit Shutoff (Typical)
- 13-mΩ High-Side MOSFET
- 2-µA Maximum Standby Supply Current
- **Built-in Soft-Start**
- Reverse Current Blocking when Disabled
- 8 kV / 15 kV System-Level ESD Capable
- 10-Pin SON (3-mm × 3-mm) Package with Wettable Flanks

Applications

- Automotive USB Ports/Hubs
- Automotive Internal Load Switch

3 Description

TPS2559-Q1 power-distribution intended for applications where a low resistance, precision current limit switch is required or heavy capacitive loads are encountered. The TPS2559-Q1 provides up to 5.5 A of continuous load current with a precise current limit set by a single resistor to ground. Output current is maintained at a safe level by switching into a constant-current mode when the output load exceeds the current-limit threshold. During overload events the output current is limited to the level set by $R_{(ILIM)}$. If a persistent overload occurs, the device goes into thermal shutoff to prevent damage to the TPS2559-Q1.

The power-switch rise and fall times are controlled to minimize current surges during turn on or off. The FAULT logic output asserts low during overcurrent or overtemperature conditions.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS2559-Q1	VSON (10)	3.00mm x 3.00mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Simplified Schematic

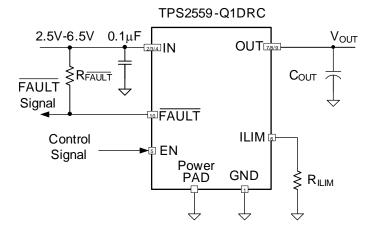




Table of Contents

1	Features 1		9.2 Functional Block Diagram	10
2	Applications 1		9.3 Feature Description	10
3	Description 1		9.4 Device Functional Modes	11
4	Revision History2	10	Application and Implementation	1 <mark>2</mark>
5	Device Comparison Table 3		10.1 Application Information	12
6	Pin Configuration and Functions		10.2 Typical Application	12
7	Specifications4	11	Power Supply Recommendations	19
•	7.1 Absolute Maximum Ratings	12	Layout	20
	7.2 ESD Ratings		12.1 Layout Guidelines	<mark>20</mark>
	7.3 Recommended Operating Conditions		12.2 Layout Example	20
	7.4 Thermal Information	13	Device and Documentation Support	21
	7.5 Electrical Characteristics		13.1 Community Resources	21
	7.6 Timing Requirements		13.2 Trademarks	21
	7.7 Typical Characteristics		13.3 Electrostatic Discharge Caution	21
8	Parameter Measurement Information9		13.4 Glossary	<mark>21</mark>
9	Detailed Description 10 9.1 Overview 10	14	Mechanical, Packaging, and Orderable Information	21

4 Revision History

DATE	REVISION	NOTES
December 2015	*	Initial release.

Submit Documentation Feedback

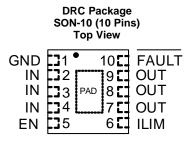


www.ti.com

5 Device Comparison Table

Device	Operation Range (V)	OCP Mode	ICONT. Adj. Range (A)	R _{DS(on)} (mΩ)	l _{os} tolerance	Package
TPS2559-Q1	2.5 - 6.5	Auto Retry	5.5	13	±4.7% at 4.7 A	DRC (SON-10)
TPS2553-Q1	2.5 - 6.5	Auto Retry	1.2	85 (DBV)	±6.8% at 1.3 A	DBV (SOT-23)
TPS2556/7-Q1	2.5 - 6.5	Auto Retry	5	22	±6.3% at 4.5 A	DRB (SON-8)
TPS2561A-Q1 (Dual Channels)	2.5 - 6.5	Auto Retry	2.5	44	2.1 A to 2.5 A	DRC (SON-10)
TPS25200-Q1 (With OVP protection)	2.5 - 6.5 (Withstand up to 20V)	Auto Retry	2.5	60	±6.3% at 2.7 A	DRV (SON-6)

6 Pin Configuration and Functions



Pin Functions

PIN		TYPE	DESCRIPTION
NAME	NO.	ITPE	DESCRIPTION
GND	1		Ground connection, connect externally to PowerPAD
IN	2,3,4	I	Input voltage, connect a 0.1 μF or greater ceramic capacitor from IN to GND as close to the IC as possible
EN	5	1	Enable input, logic high turns on power switch.
ILIM	6	0	External resistor used to set current-limit threshold; recommended. 24.9 k Ω ≤ R _(ILIM) ≤ 100 k Ω .
OUT	7,8,9	0	Power-switch output
FAULT	10	0	Active-low open-drain output, asserted during over-current or overtemperature conditions.
PowerPAD™	PAD		Internally connected to GND; used to heat-sink the part to the circuit board traces. Connect PowerPAD to GND pin externally.

TEXAS INSTRUMENTS

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1) (2)

		MIN	I MAX	UNIT
Voltage range	IN, OUT, EN, ILIM, FAULT	-0.3	3 7	V
	IN to OUT	-7	7	V
Continuous output current, I _{OUT}	OUT	In	ternally Limited	mA
Continuous FAULT sink current			20	mA
ILIM source current			ternally Limited	mA
Maximum junction temperature, T _J			to OTSD2	°C
Storage temperature, T _{stg}			150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Voltages are referenced to GND unless otherwise noted.

7.2 ESD Ratings

				VALUE	UNIT
	Human body model (HBM), ESD stress voltage, all pins (2)			±2000	
Electrostatic	Charged device model (CDM), ESD stress voltage, all pins ⁽³⁾		±750	\/	
V _(ESD)	discharge ⁽¹⁾	Contain Laurel (4)	Contact discharge	±8000	V
		System Level (4)	Air discharge	±15000	

⁽¹⁾ Electrostatic discharge (ESD) to measure device sensitivity or immunity to damage caused by assembly-line electrostatic discharges into the device.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{IN}	Input voltage, IN	2.5	6.5	V
V _{EN}	Input voltage, EN	0	6.5	V
I _{OUT}	Continuous output current of OUT		5.5	Α
	Continuous FAULT sink current		10	mA
R _(ILIM)	Recommended resistor limit range (1)	24.9	100	kΩ
TJ	Operating junction temperature	-40	125	°C

⁽¹⁾ $R_{(ILIM)}$ is the resistor from ILIM pin to GND and ILIM pin can be shorted to GND.

7.4 Thermal Information

	THERMAL METRIC ⁽¹⁾	TPS2559-Q1	
	THERMAL METRIC**	DRC (10 PINS)	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	40.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	45.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	15.9	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.4	°C/W
ΨЈВ	Junction-to-board characterization parameter	15.7	°C/W
R ₀ JC(bot)	Junction-to-case (bottom) thermal resistance	2.8	°C/W

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

⁽²⁾ The passing level per AEC-Q100 Classification H2.

⁽³⁾ The passing level per AEC-Q100 Classification C5.

⁽⁴⁾ Surges per EN61000-4-2, 1999 applied between USB and output ground of the TPS2559EVM (SLUUB15) evaluation module (documentation available on the Web.) These were the test levels, not the failure threshold.



www.ti.com

7.5 Electrical Characteristics

Conditions are $-40^{\circ}\text{C} \le \text{T}_{\text{J}} \le 125^{\circ}\text{C}$, $2.5 \text{ V} \le \text{V}_{\text{IN}} \le 6.5 \text{ V}$, $\text{V}_{(\text{EN})} = \text{V}_{\text{IN}}$, $\text{R}_{(\text{ILIM})} = 49.9 \text{ k}\Omega$. Positive current are into pins. Typical value is at 25°C. All voltages are with respect to GND (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER	SWITCH					
D	Land Outset Besisters (1)	T _J = 25°C		13	16	0
R _{DS(on)}	Input - Output Resistance ⁽¹⁾	-40°C ≤ T _J ≤ 125°C			21	mΩ
ENABLE	E INPUT EN					
	EN turn on/off threshold		0.66		1.1	V
	Hysteresis			55 ⁽²⁾		mV
I _(EN)	Input current	V _(EN) = 0 V or V _(EN) = 6.5 V	-1		1	μA
CURRE	NT LIMIT					
		$R_{(ILIM)} = 24.9 \text{ k}\Omega$	4490	4730	4931	
		$R_{(ILIM)} = 44.2k\Omega$	2505	2660	2805	
	OUT about singuit assument limit	$R_{(ILIM)} = 49.9k\Omega$	2215	2360	2490	
los	OUT short circuit current limit	$R_{(ILIM)} = 61.9 \text{ k}\Omega$	1780	1900	2015	2015 mA 1265 7460
		$R_{(ILIM)} = 100 \text{ k}\Omega$	1080	1180	1265	
		ILIM pin short to GND (R _(ILIM) = 0)	5860	6700	7460	
SUPPLY	CURRENT					
I _(IN_OFF)	Disabled, IN supply current	V _(EN) = 0 V, No load on OUT		0.1	2	μA
	Facility IN sometimes of	$R_{(ILIM)} = 100 \text{ k}\Omega$, no load on OUT		97	125	
I _(IN_ON)	Enabled, IN supply current	$R_{(ILIM)} = 24.9 \text{ k}\Omega$, no load on OUT		107	135	μΑ
I _(REV)	Reverse leakage current	V_{OUT} = 6.5 V, V_{IN} = 0 V, T_{J} = 25°C, Measure I_{OUT}		0.01	1	μΑ
UNDER	VOLTAGE LOCKOUT					
V_{UVLO}	IN rising UVLO threshold voltage			2.36	2.45	V
	Hysteresis			35 ⁽²⁾		mV
FAULT						
V _{OL}	Output low voltage	I _{FAULT} = 1 mA			180	mV
	Off-state leakage	$V_{\overline{FAULT}} = 6.5 \text{ V}$			1	μΑ
THERM	AL SHUTDOWN	•	·			
OTSD2	Thermal shutdown threshold		155			°C
OTSD1	Thermal shutdown threshold in current-limit		135			-0
	Hysteresis			20 (2)		
		•				

⁽¹⁾ Pulse-testing techniques maintain junction temperature close to ambient temperature. Thermal effects must be taken into account separately

⁽²⁾ These parameters are provided for reference only, and don't constitute part of TI's published device specifications for purposes of TI's product warranty.

TEXAS INSTRUMENTS

7.6 Timing Requirements

Conditions are $-40^{\circ}\text{C} \le \text{T}_{\text{J}} = \le 125^{\circ}\text{C}$, $2.5 \text{ V} \le \text{V}_{\text{IN}} \le 6.5 \text{ V}$, $\text{V}_{(\text{EN})} = \text{V}_{\text{IN}}$, $\text{R}_{(\text{ILIM})} = 49.9 \text{ k}\Omega$. Positive current are into pins. Typical value is at 25°C. All voltages are with respect to GND (unless otherwise noted).

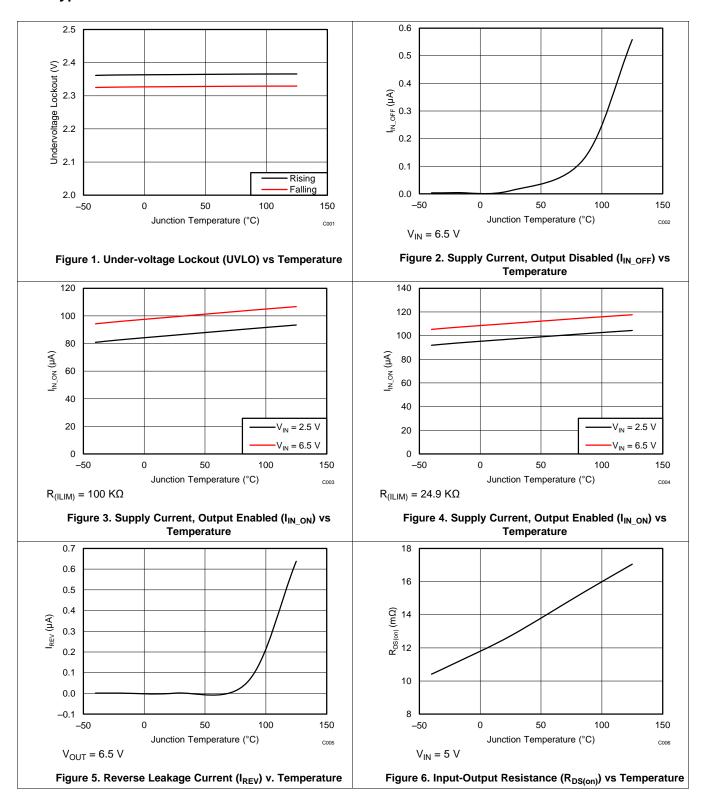
	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
POW	ER SWITCH						
	OLIT valtage rice time	V _{IN} = 6.5 V		2.6	3.44	5.2	
t _r	OUT voltage rise time	V _{IN} = 2.5 V	C_L = 1 μ F, R_L = 100 Ω , See Figure 13	1.3	2.01	3.9	
	OUT voltage fall time	V _{IN} = 6.5 V		0.7	0.89	1.3	ms
t _f	Oo'r voltage fall time	$V_{IN} = 2.5 \text{ V}$		0.42	0.58	1.04	
ENA	ENABLE INPUT EN						
t _{on}	OUT voltage turn-on time	C 1E D 100.0	$C_L = 1 \mu F$, $R_L = 100 \Omega$, See Figure 14			15	
t _{off}	OUT voltage turn-off time	$C_L = 1 \mu F, R_L = 100 \Omega$	2, See Figure 14			8	ms
CUR	RENT LIMIT						
t _{IOS}	Short-circuit response time (1)	$V_{IN} = 5 \text{ V}, R_{SHORT} = 50 \text{ m}\Omega, \text{ See Figure 15}$			3.5 ⁽¹⁾		μs
FAUI	<u>.T</u>						
	FAULT deglitch	FAULT assertion or d condition	6	9	13	ms	

⁽¹⁾ This parameter is provided for reference only and does not constitute part of TI's published device specifications for purposes of TI's product warranty

Submit Documentation Feedback

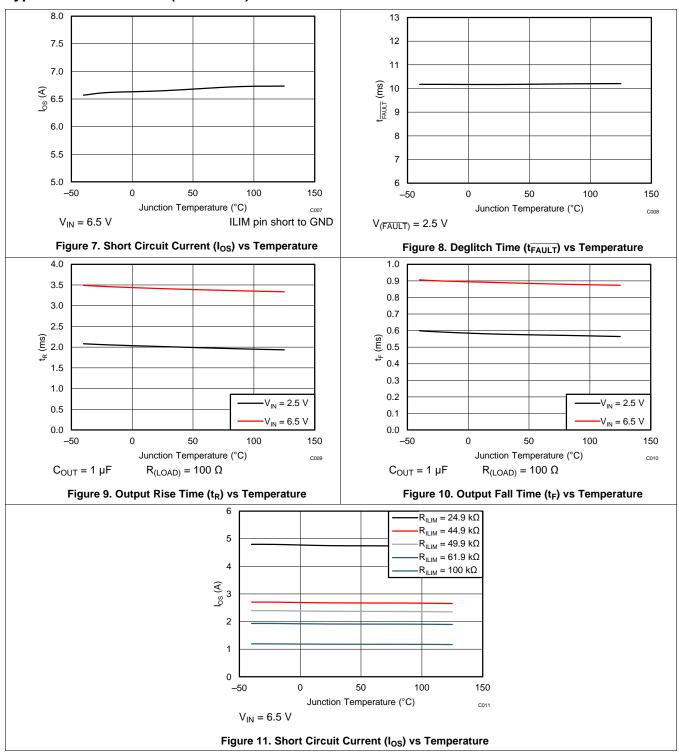


7.7 Typical Characteristics



TEXAS INSTRUMENTS

Typical Characteristics (continued)



Submit Documentation Feedback

Copyright © 2015, Texas Instruments Incorporated

8 Parameter Measurement Information

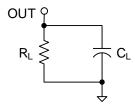


Figure 12. Output Rise/Fall time Test Load

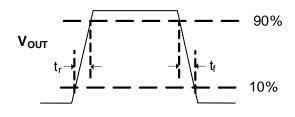


Figure 13. Power-On and Off Timing

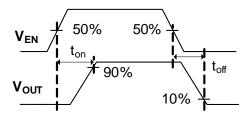


Figure 14. Enable Timing, Active High Enable

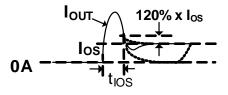


Figure 15. Output Short Circuit Parameters

Copyright © 2015, Texas Instruments Incorporated

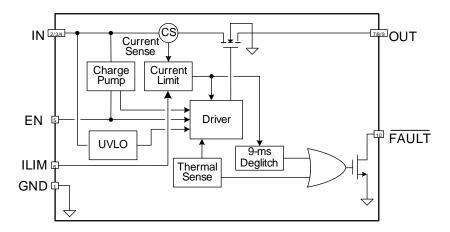
TEXAS INSTRUMENTS

9 Detailed Description

9.1 Overview

The TPS2559-Q1 is a current-limited, power-distribution switch using N-channel MOSFETs for applications where short circuits or heavy capacitive loads will be encountered. This device allows the user to program the current-limit via an external resistor and the maximum continuous output current up to 5.5 A. This device incorporates an internal charge pump and the gate drive circuitry necessary to drive the N-channel MOSFET. The charge pump supplies power to the driver circuit and provides the necessary voltage to pull the gate of the MOSFET above the source. The charge pump operates from input voltages as low as 2.5 V and requires little supply current. The driver controls the gate voltage of the power switch. The driver incorporates circuitry that controls the rise and fall times of the output voltage to limit large current and voltage surges and provides built-in soft-start functionality. The TPS2559-Q1 limits the output current to the programmed current-limit threshold I_{OS} during an overcurrent or short-circuit event by reducing the charge pump voltage driving the N-channel MOSFET and operating it in the linear range of operation. The result of limiting the output current to I_{OS} reduces the output voltage at OUT because N-channel MOSFET is no longer fully enhanced.

9.2 Functional Block Diagram



9.3 Feature Description

9.3.1 Thermal Sense

The TPS2559-Q1 self protects by using two independent thermal sensing circuits that monitor the operating temperature of the power switch and disable operation if the temperature exceeds recommended operating conditions. The TPS2559-Q1 device operates in constant-current mode during an over-current condition, which increases the voltage drop across power switch. The power dissipation in the package is proportional to the voltage drop across the power switch, which increases the junction temperature during an over-current condition. The first thermal sensor (OTSD1) turns off the power switch when the die temperature exceeds 135°C (min) and the part is in current limit. Hysteresis is built into the thermal sensor, and the switch turns on after the device has cooled approximately 20°C.

The TPS2559-Q1 also has a second ambient thermal sensor (OTSD2). The ambient thermal sensor turns off the power switch when the die temperature exceeds 155°C (min) regardless of whether the power switch is in current limit and will turn on the power switch after the device has cooled approximately 20°C. The TPS2559-Q1 continues to cycle off and on until the fault is removed.

0 Submit Documentation Feedback

www.ti.com

Feature Description (continued)

9.3.2 Overcurrent Protection

The TPS2559-Q1 responds to overcurrent conditions by limiting their output current to IOS. When an overload condition is present, the device maintains a constant output current, with the output voltage determined by ($I_{OS} \times R_{LOAD}$). Two possible overload conditions can occur.

The first condition is when a short circuit or partial short circuit is present when the device is powered-up or enabled. The output voltage is held near zero potential with respect to ground and the TPS2559-Q1 ramps the output current to I_{OS}. The TPS2559-Q1 limits the current to I_{OS} until the overload condition is removed or the device begins to thermal cycle (see Figure 24).

The second condition is when a short circuit, partial short circuit, or transient overload occurs while the device is enabled and powered on. The device responds to the overcurrent condition within time t_{IOS} (see Figure 15). The response speed and shape will vary with the overload level, input circuit, and rate of application. The current-limit response will vary between simply settling to I_{OS} , or turnoff and controlled return to IOS. Similar to the previous case, the TPS2559-Q1 limits the current to I_{OS} until the overload condition is removed or the device begins to thermal cycle.

The TPS2559-Q1 thermal cycles if an overload condition is present long enough to activate thermal limiting in any of the above cases. The device turns off when the junction temperature exceeds 135°C (min) while in current limit. The device remains off until the junction temperature cools 20°C (typ) and then restarts. The TPS2559-Q1 cycles on/off until the overload is removed (see Figure 25).

9.3.3 FAULT Response

The FAULT open-drain output is asserted (active low) during an over-current or over-temperature condition. The TPS2559-Q1 asserts the FAULT signal until the fault condition is removed and the device resumes normal operation. The TPS2559-Q1 is designed to eliminate false FAULT reporting by using an internal delay "deglitch" circuit for over-current (9-ms typ.) conditions without the need for external circuitry. This ensures that FAULT is not accidentally asserted due to normal operation such as starting into a heavy capacitive load. The deglitch circuitry delays entering and leaving current-limit induced fault conditions. The FAULT signal is not deglitched when the MOSFET is disabled due to an over-temperature condition but is deglitched after the device has cooled and begins to turn on. This unidirectional deglitch prevents FAULT oscillation during an over-temperature event.

9.4 Device Functional Modes

9.4.1 Operation with VIN Undervoltage Lockout (UVLO) Control

The undervoltage lockout (UVLO) circuit disables the power switch until the input voltage reaches the UVLO turnon threshold. Built-in hysteresis prevents unwanted on/off cycling due to input voltage droop during turn on.

9.4.2 Operation with EN Control

The logic enable controls the power switch and device supply current. The supply current is reduced to less than 2-µA when a logic low is present on EN. A logic high input on EN enables the driver, control circuits, and power switch. The enable input is compatible with both TTL and CMOS logic levels.

10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The TPS2559-Q1 current limited power switch uses N-channel MOSFETs in applications requiring up to 5.5 A of continuous load current. The device enters constant-current mode when the load exceeds the current limit threshold.

The TPS2559-Q1 power switch is used to protect the up-stream power supply when the output is overloaded.

10.2 Typical Application

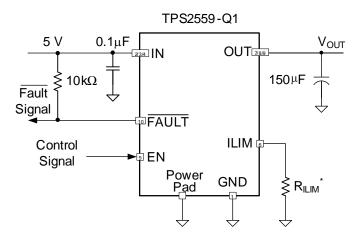


Figure 16. Typical TPS2559-Q1 Power Switch

Use the I_{OS} in the *Electrical Characteristics* table or I_{OS} in Equation 1 to select the R_{ILIM}.

10.2.1 Design Requirements

For this design example, use the following as the input parameters.

DESIGN PARAMETERS	EXAMPLE VALUE
Input Operation Voltage	5 V
Rating Current	3A or 4.5A
Minimum Current Limit	3A
Maximum Current Limit	5A

When choose power switch, there are some several general steps:

- 1. What is the power rail, 3.3 V or 5 V, and then choose the operation range of power switch can cover the power rail.
- 2. What is the normal operation current, for example, the maximum allowable current drawn by portable equipment for USB 2.0 port is 500mA, so the normal operation current is 500mA and the minimum current limit of power switch must exceed 500 mA to avoid false trigger during normal operation.
- 3. What is the maximum allowable current provided by up-stream power, and then decide the maximum current limit of power switch that must lower it to ensure power switch can protect the up-stream power when overload is encountered at the output of power switch.

Submit Documentation Feedback



NOTE

Choosing power switch with tighter current limit tolerance can loosen the up-stream power supply design.

10.2.2 Detailed Design Procedure

10.2.2.1 Step by Step Design Procedure

To begin the design process a few parameters must be decided upon. The designer needs to know the following:

- Normal Input Operation Voltage
- Rating Current
- Minimum Current Limit
- Maximum Current Limit

10.2.2.2 Input and Output Capacitance

Input and output capacitance improves the performance of the device; the actual capacitance should be optimized for the particular application. For all applications, a $0.1\mu F$ or greater ceramic bypass capacitor between IN and GND is recommended as close to the device as possible for local noise decoupling. This precaution reduces ringing on the input due to power-supply transients. Additional input capacitance may be needed on the input to reduce voltage undershoot from exceeding the UVLO of other load share one power rail with TPS2559-Q1 or overshoot from exceeding the absolute-maximum voltage of the device during heavy transient conditions. This is especially important during bench testing when long, inductive cables are used to connect the evaluation board to the bench power supply.

Output capacitance is not required, but placing a high-value electrolytic capacitor on the output pin is recommended when large transient currents are expected on the output to reduce the undershoot, which caused by the inductance of the output power bus just after a short has occurred and the TPS2559-Q1 has abruptly reduced OUT current. Energy stored in the inductance will drive the OUT voltage down and potentially negative as it discharges.

10.2.2.3 Programming the Current-Limit Threshold

The overcurrent threshold is user programmable via an external resistor. The TPS2559-Q1 uses an internal regulation loop to provide a regulated voltage on the ILIM pin. The current-limit threshold is proportional to the current sourced out of ILIM. The recommended 1% resistor range for $R_{(ILIM)}$ is 24.9 k $\Omega \leq R_{(ILIM)} \leq 100$ k Ω to ensure stability of the internal regulation loop.

When ILIM pin short to GND (single point failure), maximum current limit is less than 8 A over temperature and process variation.

Many applications require that the minimum current limit is above a certain current level or that the maximum current limit is below a certain current level, so it is important to consider the tolerance of the overcurrent threshold when selecting a value for $R_{(ILIM)}$. The equations and the graph below can be used to estimate the minimum and maximum variation of the current-limit threshold for a predefined resistor value within $R_{(ILIM)}$ is 24.9 $k\Omega \le R_{(ILIM)} \le 100 \ k\Omega$. This variation is an approximation only and does not take into account, for example, the resistor tolerance. For examples of more-precise variation of I_{OS} refer to the current-limit section of the *Electrical Characteristics* table.

$$\begin{split} I_{OSmax}(mA) &= \frac{118848 \ V}{R_{(ILIM)}^{0.9918} k\Omega} + 30 \\ I_{OSnom}(mA) &= \frac{118079 \ V}{R_{(ILIM)}^{1.0008} k\Omega} \\ I_{OSmin}(mA) &= \frac{113325 \ V}{R_{(ILIM)}^{1.0010} k\Omega} - 47 \end{split}$$

(1)

 $24.9 \text{ k}\Omega \leq R_{\text{(ILIM)}} \leq 100 \text{ k}\Omega$

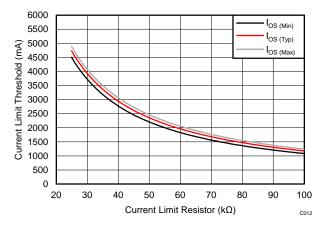


Figure 17. Current-Limit vs R_(ILIM)

10.2.2.4 Design Above a Minimum Current Limit

Some applications require that current limiting cannot occur below a certain threshold. For this example, assume that 3 A must be delivered to the load so that the minimum desired current-limit threshold is 3000 mA. Use the I_{OS} equations and Figure 17 to select $R_{(ILIM)}$.

$$I_{OSmin}(mA) = 3000 mA$$

$$I_{OSmin}(mA) = \frac{113325 \text{ V}}{R_{(ILIM)}^{1.0010} k\Omega} - 47$$

$$R_{\text{(ILIM)}}(k\Omega) = \left(\frac{113325}{I_{\text{OS(min)}} + 47}\right)^{\frac{1}{1.0010}} = \left(\frac{113325}{3000 + 47}\right)^{\frac{1}{1.0010}} = 37.06 \text{ k}\Omega$$
(2)

Select the closest 1% resistor less than the calculated value: $R_{(ILIM)} = 36.5 \text{ k}\Omega$. This sets the minimum current-limit threshold at 3016 A.

$$I_{OSmin}(mA) = \frac{113325 \text{ V}}{R_{(ILIM)}^{1.0010} k\Omega} - 47 = \frac{113325}{\left(36.5 \times 1.01\right)^{1.0010}} - 47 = 3016 \text{ mA}$$
(3)

Use the I_{OS} equations, Figure 17, and the previously calculated value for $R_{(ILIM)}$ to calculate the maximum resulting current-limit threshold.

$$I_{OSmax}(mA) = \frac{118848}{R_{(ILIM)}^{0.9918}} + 30 = \frac{118848}{(36.5 \times 0.99)^{0.9918}} + 30 = 3417 \text{ mA}$$
(4)

The resulting maximum current-limit threshold minimum is 3016 mA and maximum is 3417 mA with a 36.5 k Ω ± 1%

10.2.2.5 Design Below a Maximum Current Limit

Some applications require that current limiting must occur below a certain threshold. For this example, assume that 5A must be delivered to the load so that the minimum desired current-limit threshold is 5000 mA. Use the I_{OS} equations and Figure 17 to select $R_{(ILIM)}$.

$$I_{OSmax}(mA) = 5000 \text{ mA}$$

$$I_{OSmax}(mA) = \frac{118848}{R_{(ILIM)}^{0.9918} k\Omega} + 30$$

$$R_{\text{(ILIM)}}(k\Omega) = \left(\frac{118848}{I_{\text{OS(max)}} - 30}\right)^{\frac{1}{0.9918}} = \left(\frac{118848}{5000 - 30}\right)^{\frac{1}{0.9918}} = 24.55 \text{ k}\Omega$$
(5)

Submit Documentation Feedback

Copyright © 2015, Texas Instruments Incorporated

www.ti.com SLVSD03 – DECEMBER 2015

Select the closest 1% resistor less than the calculated value: R_{ILIM} = 24.9 k Ω . This sets the maximum current-limit threshold at 4950 A.

$$I_{OSmax}(mA) = \frac{118848}{R_{(ILIM)}^{0.9918}k\Omega} + 30 = \frac{118848}{(24.9 \times 0.99)^{0.9918}} + 30 = 4980 \text{ mA}$$
(6)

Use the I_{OS} equations, Figure 17, and the previously calculated value for $R_{(ILIM)}$ to calculate the minimum resulting current-limit threshold.

$$I_{OSmin}(mA) = \frac{113325}{R_{(ILIM)}^{1.0010}} - 47 = \frac{113325}{(24.9 \times 1.01)^{1.0010}} - 47 = 4445 \text{ mA}$$
(7)

The resulting minimum current-limit threshold minimum is 4445 mA and maximum is 4980 mA with a 24.9 k Ω ± 1%.

10.2.2.6 Accounting for Resistor Tolerance

The previous sections described the selection of $R_{(ILIM)}$ given certain application requirements and the importance of understanding the current-limit threshold tolerance. The analysis focused only on the TPS2559-Q1 is bounded by an upper and lower tolerance centered on a nominal resistance. The additional R_{ILIM} resistance tolerance directly affects the current-limit threshold accuracy at a system level. Table 1 shows a process that accounts for worst-case resistor tolerance assuming 1% resistor values.

Step one follows the selection process outlined in the application examples above.

Step two determines the upper and lower resistance bounds of the selected resistor.

Step three uses the upper and lower resistor bounds in the IOS equations to calculate the threshold limits.

It is important to use tighter tolerance resistors, that is, 0.5% or 0.1%, when precision current limiting is desired.

Table 1. Common R_(ILIM) Resistor Selections

DESIRED NOMINAL	IDEAL	CLOSEST 1%	RESISTOR TOLERANCE		ACTUAL LIMITS		
CURRENT LIMIT (mA)	RESISTOR (kΩ)	RESISTOR (kΩ)	1% LOW (kΩ)	1% HIGH (kΩ)	I _{OS} MIN (mA)	I _{OS} NOM (mA)	I _{OS} MAX (mA)
1250	94.1	93.1	92.2	94	1152.7	1263.7	1368.2
1500	78.4	78.7	77.9	79.5	1372.5	1495.1	1610.9
1750	67.2	66.5	65.8	67.2	1633.2	1769.7	1893.3
2000	58.8	59	58.4	59.6	1847	1994.8	2133.7
2250	52.3	52.3	51.8	52.8	2089.9	2550.6	2400.9
2500	47.1	47.5	47	48	2306	2478.2	2638.4
2750	42.8	43.2	42.8	43.6	2540.5	2725.1	2895.8
3000	39.2	39.2	38.8	39.6	2804.8	3003.4	3185.7
3250	36.2	36.5	36.1	36.9	3016	3225.7	3417.2
3500	33.6	34	33.7	34.3	3241.4	3463.1	3664.1
3750	31.4	31.6	31.3	31.9	3491.5	3726.4	3937.8
4000	29.4	29.4	29.1	29.7	3756.5	4005.4	4227.7
4250	27.7	28	27.7	28.3	3946.9	4205.9	4435.8
4500	26.2	26.1	25.8	26.4	4237.9	4512.3	4753.9
4750	24.8	24.9	24.7	25.1	4444.6	4729.9	4979.6

SLVSD03 – DECEMBER 2015 www.ti.com

TEXAS INSTRUMENTS

10.2.2.7 Power Dissipation and Junction Temperature

The low on-resistance of the N-channel MOSFET allows small surface-mount packages to pass large currents. It is good design practice to estimate power dissipation and junction temperature. The below analysis gives an approximation for calculating junction temperature based on the power dissipation in the package. However, it is important to note that thermal analysis is strongly dependent on additional system level factors. Such factors include air flow, board layout, copper thickness and surface area, and proximity to other devices dissipating power. Good thermal design practice must include all system level factors in addition to individual component analysis. Begin by determining the $r_{DS(on)}$ of the N-channel MOSFET relative to the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest and read $r_{DS(on)}$ from the typical characteristics graph. Using this value, the power dissipation can be calculated using Equation 8:

$$P_{D} = r_{DS(on)} \times I_{OUT}^{2}$$
(8)

Where:

 P_D = Total power dissipation (W)

 $r_{DS(on)}$ = Power switch on-resistance (Ω)

I_{OUT} = Maximum current-limit threshold (A)

This step calculates the total power dissipation of the N-channel MOSFET.

Finally, calculate the junction temperature:

$$T_{J} = P_{D} \times \theta_{JA} + T_{A} \tag{9}$$

Where:

 $T_A = Ambient temperature (°C)$

 θ_{JA} = Thermal resistance (°C/W)

P_D = Total power dissipation (W)

Compare the calculated junction temperature with the initial estimate. If they are not within a few degrees, repeat the calculation using the "refined" $r_{DS(on)}$ from the previous calculation as the new estimate. Two or three iterations are generally sufficient to achieve the desired result. The final junction temperature is highly dependent on thermal resistance θ_{JA} and thermal resistance is highly dependent on the individual package and board layout.

10.2.2.8 Auto-Retry

Some applications require that an overcurrent condition disables the part momentarily during a fault condition and re-enables after a pre-set time. This auto-retry functionality can be implemented with an external resistor and capacitor. During a fault condition, FAULT pulls low EN. The part is disabled when EN is pulled below the turn-off threshold, and FAULT goes high impedance allowing $C_{(RETRY)}$ to begin charging. The part re-enables when the voltage on EN reaches the turn-on threshold. The part will continue to cycle in this manner until the fault condition is removed. The auto-retry cycling time is determined by the resistor/capacitor time constant, TPS2559-Q1 turn on time and FAULT deglitch time (see Figure 28).

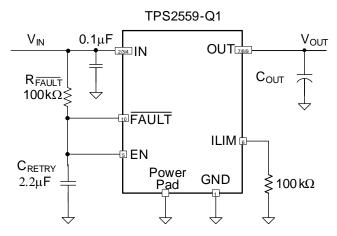


Figure 18. Auto-Retry Circuit

Submit Documentation Feedback

Some applications require auto-retry functionality and the ability to enable/disable with an external logic signal. Figure 19 shows how an external logic signal can drive EN through $R_{(FAULT)}$ and maintain auto-retry functionality. The resistor/capacitor time constant determines the auto-retry time-out period.

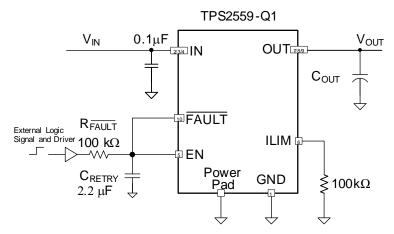


Figure 19. Auto-Retry Circuit with External EN Signal

If need to implement latch-off, refer to application report (SLVA282A).

10.2.2.9 Two-level Current-limit

Some applications require different current-limit thresholds depending on external system conditions. Figure 20 shows an implementation for an externally-controlled, two-level current-limit circuit. The current-limit threshold is set by the total resistance from ILIM to GND (see previously discussed *Programming the Current-Limit Threshold* section). A logic-level input enables/disables MOSFET Q1 and changes the current-limit threshold by modifying the total resistance from ILIM to GND (see Figure 29 and Figure 30). Additional MOSFET/resistor combinations can be used in parallel to Q1/R2 to increase the number of additional current-limit levels.

NOTE

ILIM should never be driven directly with an external signal.

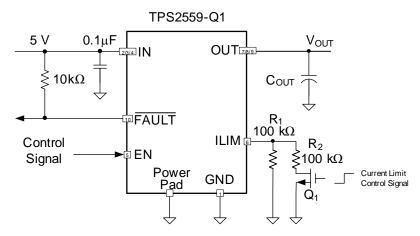
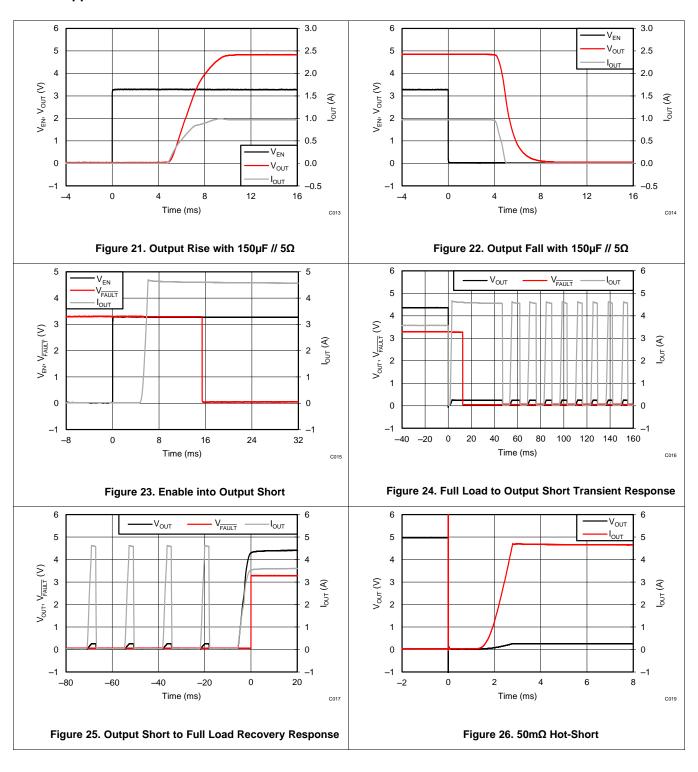
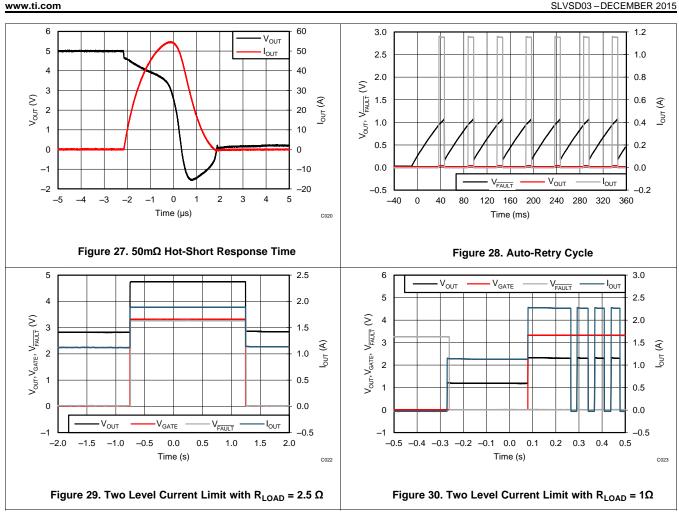


Figure 20. Two-Level Current-Limit Circuit

10.2.3 Application Curves







Power Supply Recommendations

Design of the devices is for operation from an input voltage supply range of 2.5 V to 6.5 V. The current capability of the power supply should exceed the maximum current limit of the power switch.

12 Layout

12.1 Layout Guidelines

- Place the 100-nF bypass capacitor near the IN and GND pins, and make the connections using a low-inductance trace.
- Placing a high-value electrolytic capacitor and a 100-nF bypass capacitor on the output pin is recommended when large transient currents are expected on the output.
- The traces routing the R_{ILIM} resistor to the device should be as short as possible to reduce parasitic effects on the current limit accuracy.
- The PowerPAD should be directly connected to PCB ground plane using wide and short copper trace.

12.2 Layout Example

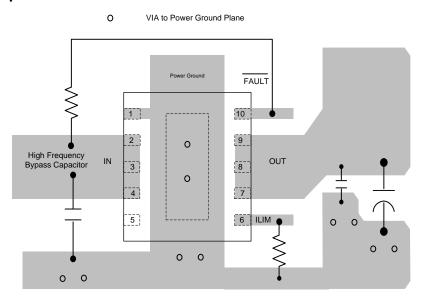


Figure 31. TPS2559-Q1 Board Layout

20

www.ti.com

13 Device and Documentation Support

13.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Lise

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

13.2 Trademarks

PowerPAD, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 10-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
TPS2559QWDRCRQ1	Active	Production	VSON (DRC) 10	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	2559Q
TPS2559QWDRCRQ1.A	Active	Production	VSON (DRC) 10	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	2559Q
TPS2559QWDRCTQ1	Active	Production	VSON (DRC) 10	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	2559Q
TPS2559QWDRCTQ1.A	Active	Production	VSON (DRC) 10	250 SMALL T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	2559Q

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents Tl's knowledge and belief as of the date that it is provided. Tl bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. Tl has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. Tl and Tl suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS2559-Q1:

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

www.ti.com 10-Nov-2025

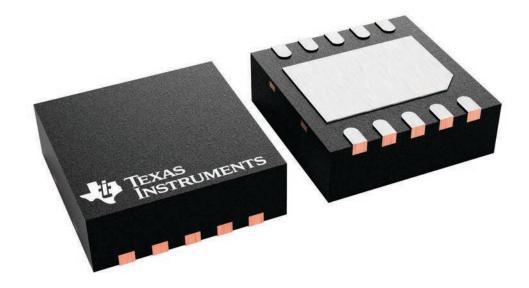
NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

3 x 3, 0.5 mm pitch

PLASTIC SMALL OUTLINE - NO LEAD

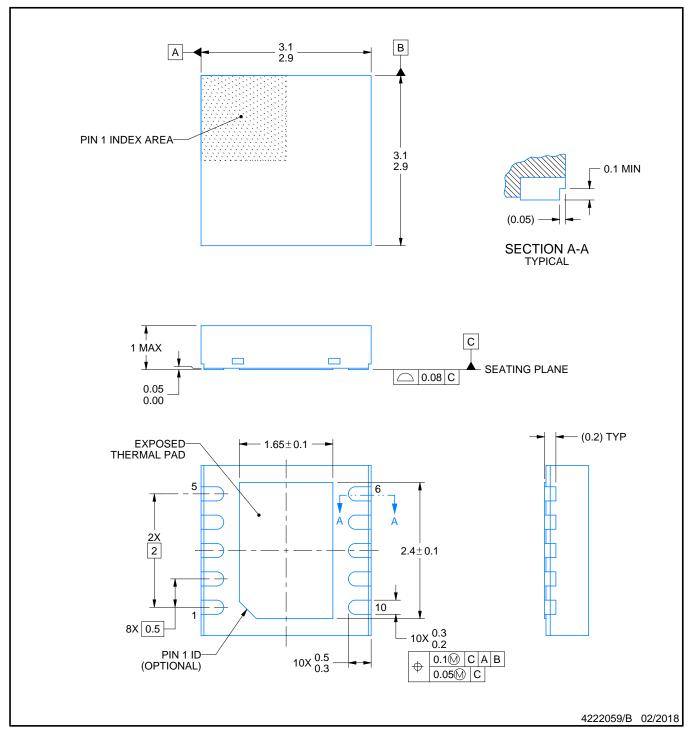
This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



INSTRUMENTS www.ti.com



PLASTIC SMALL OUTLINE - NO LEAD

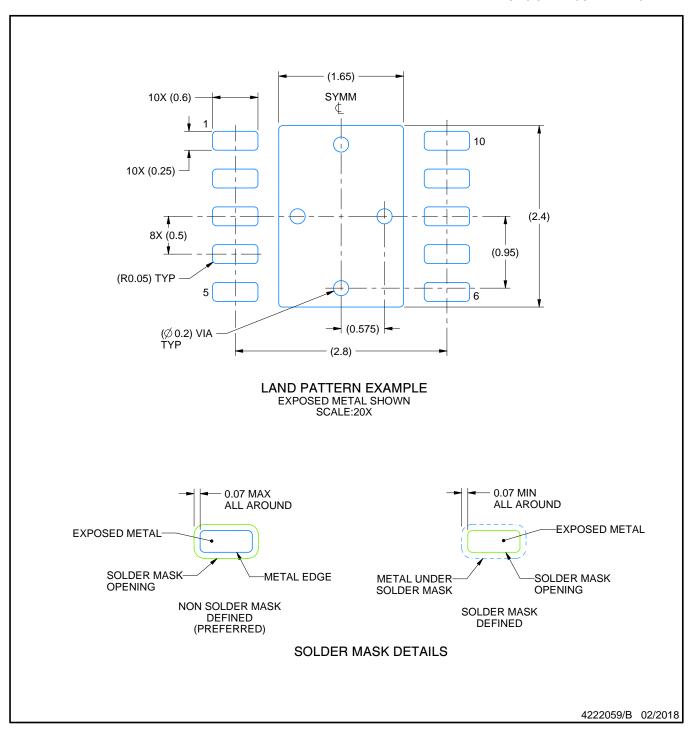


NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC SMALL OUTLINE - NO LEAD

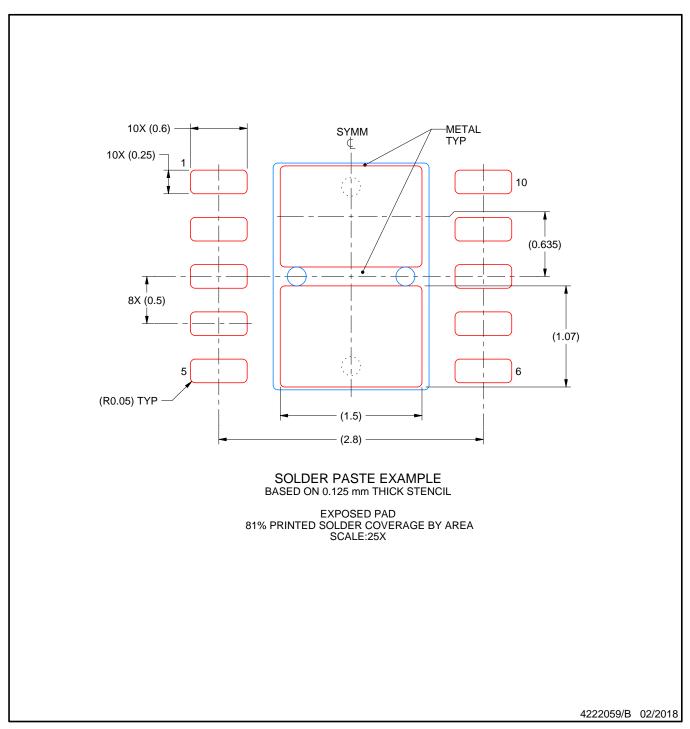


NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale, TI's General Quality Guidelines, or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025